# PRODUCT SPECIFICATION

Model No: CSM-58462VM9

# **Descriptions:**

- 4.6 Inch 5X8 Dot-Matrix Display
- Dot Pitch 15.25mm
- CSM-58462: Column Cathode, Row Anode
- Emitting Color: Super Bright Orange & Super Bright Green









CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

#### CHINA SEMICONDUCTOR CORPORATION

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#### **OPTO PLUS TECHNOLOGIES CO.,LTD**

Address:696 Shun jiang Rd.,Ji Shan St.Shaoxing, ZheJiang,China

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Spec. No.	PS-ND-08090403
Rev.	Α

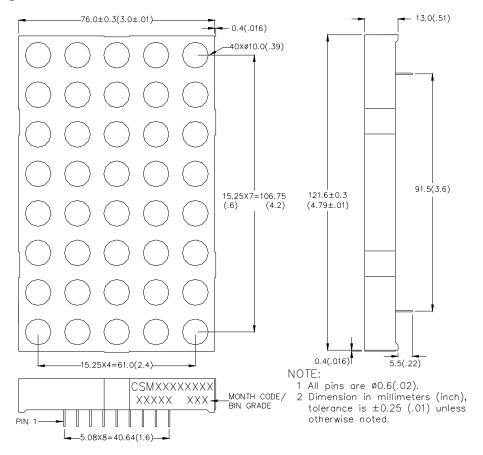
#### Features -

- 1. 4.6 inch (116.75mm) Matrix height.
- 2. Case mold type.
- 3. RoHs compliant.
- 4. Low power consumption.
- 5. Easy mounting on P.C. board or socket.

### **■** Device Selection Guide -

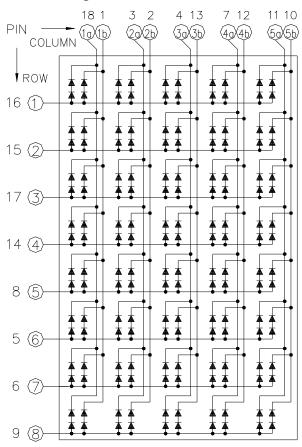
Part No.		Chip	Description	
Part NO.	Material	<b>Emitted Color</b>	Column	Row
CSM-58462VM9	AlGaInP	Super Bright Orange	Cathode	Anode
C3W-36462VW9	AlGaInP	Super Bright Green	Califode	Allode

# Package Dimensions -



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### ■ Internal Circuit Diagrams -



NOTE: "a" for Super Bright Orange color chip "b" for Super Bright Green color chip.

# ■ Absolute Maximum Rating -

Super Bright Orange			(Ta=25°ℂ)
Parameter	Symbol	Rating	Unit
Power Dissipation Per Dice	Pad	70	mW
Continuous Forward Current Per Dice	IAF	25	mA
Peak Current Per Dice(duty cycle 1/10, 1kHz)	<b>I</b> PF	90	mA
Derating Linear From 25 $^{\circ}\!$	-	0.33	m <b>A</b> /℃
Reverse Voltage Per Dice	VR	5	V
Operating Temp.	Topr	-35 ~ +85	$^{\circ}\mathbb{C}$
Storage Temp.	Tstg	-35 ~ +85	$^{\circ}\mathbb{C}$
Solder temperature 1/16 inch below seating pl	ane for 3 se	econds at 260°C	

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Super Bright Green			(Ta=25°ℂ)	
Parameter	Symbol	Rating	Unit	
Power Dissipation Per Dice	Pad	70	mW	
Continuous Forward Current Per Dice	IAF	25	mA	
Peak Current Per Dice(duty cycle 1/10, 1kHz)	<b>I</b> PF	90	mA	
Derating Linear From 25℃ Per Dice	-	0.33	m <b>A</b> /℃	
Reverse Voltage Per Dice	<b>V</b> R	5	V	
Operating Temp.	Topr	-35 ~ +85	$^{\circ}\!\mathbb{C}$	
Storage Temp.	Tstg	-35 ~ +85	$^{\circ}\! \mathbb{C}$	
Solder temperature 1/16 inch below seating plane for 3 seconds at 260 $^{\circ}\mathrm{C}$				

# ■ Electro-optical Characteristics -

Super Bright Orange						(Ta=25°ℂ)
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage Per Dot	VF	-	4.0	5.6	V	IF=20mA
Luminous Intensity Per Dot	lv	-	75	-	mcd	I==10mA
Peak Emission Wavelength	λp	-	632	-	nm	IF=20mA
Dominant Wavelength	λd	-	624	-	nm	IF=20mA
Spectrum Radiation Bandwidth	Δλ	-	20	-	nm	IF=20mA
Reverse Current	IR	-	-	100	$\mu$ A	V <sub>R</sub> =5V
<b>Luminous Intensity Matching Ratio</b>	IV-m	-	-	2:1	-	IF=10mA

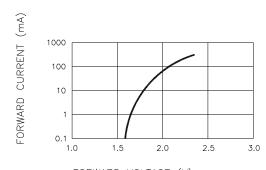
Super Bright Green						(Ta=25°ℂ)
Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage Per Dot	VF	=	4.2	5.6	V	I=20mA
Luminous Intensity Per Dot	lv	-	35	-	mcd	I=10mA
Peak Emission Wavelength	λp	-	572	-	nm	I=20mA
Dominant Wavelength	λd	-	570	-	nm	I=20mA
Spectrum Radiation Bandwidth	Δλ	-	20	-	nm	I=20mA
Reverse Current	IR	-	-	100	$\mu$ A	VR=5V
<b>Luminous Intensity Matching Ratio</b>	IV-m	-	-	2:1	-	I=10mA

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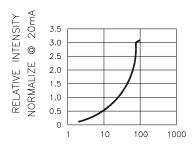
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### **■** Typical Electrical / Optical Charateristics Curves -Super Bright Orange

#### (Ta = 25°C Unless Otherwise Noted)



FORWARD VOLTAGE (V) Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE



FORWARD CURRENT(mA) Fig. 2 RELATIVE INTENSITY VS. FORWARD CURRENT

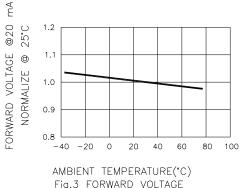
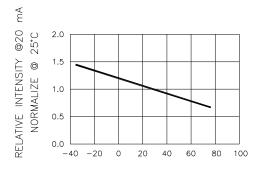
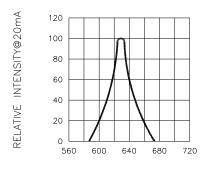


Fig. 3 FORWARD VOLTAGE VS. TEMPERATURE



AMBIENT TEMPERATURE(°C) Fig.4 RELATIVE INTENSITY VS. TEMPERATURE

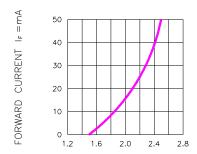


WAVELENGTH(nm) Fig.5 RELATIVE INTENSITY VS. WAVELENGTH

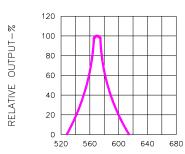
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### Super Bright Green

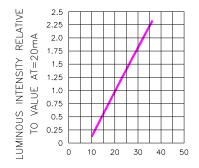
(Ta = 25°C Unless Otherwise Noted)



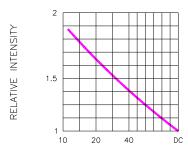
FORWARD VOLTAGE  $(V_F)$ -VOLTS Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE



WAVELENGTH  $(\lambda)$ -nm Fig.2 SPECTRAL RESPONSE



IF-FORWARD CURRENT-MA
Fig.3 RELATIVE LUMINOUS INTENSITY
VS. FORWARD CURRENT



DUTY CYCLE % PER SEGMENT (AVERAGE  $I_F = 10 \, \text{ma}$ ) Fig.5 LUMINOUS INTENSITY VS. DUTY CYCLE

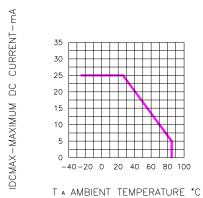


Fig.4 MAXIMUM ALLOWABLE DC CURRENT PER SEGMENT VS. A FUNCTION OF AMBIENT TEMPERATURE



Fig.6 MAX PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE  $f=1~{\rm KHz})$ 



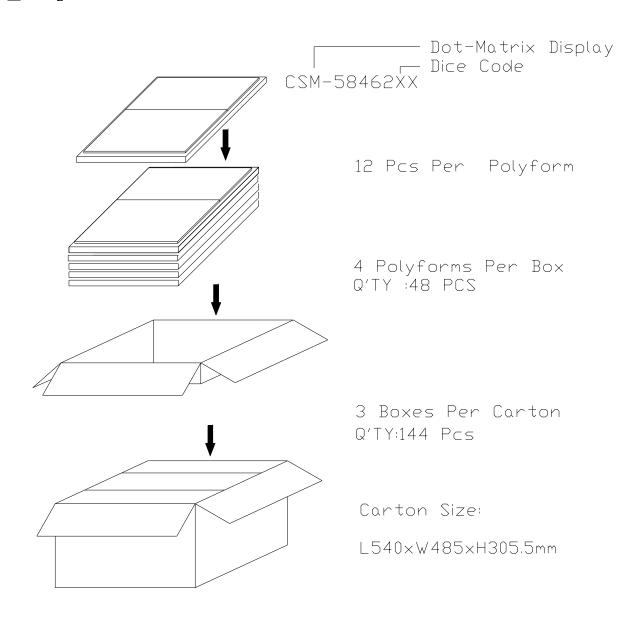
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### Package Dimensions



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